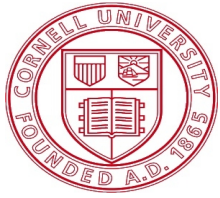
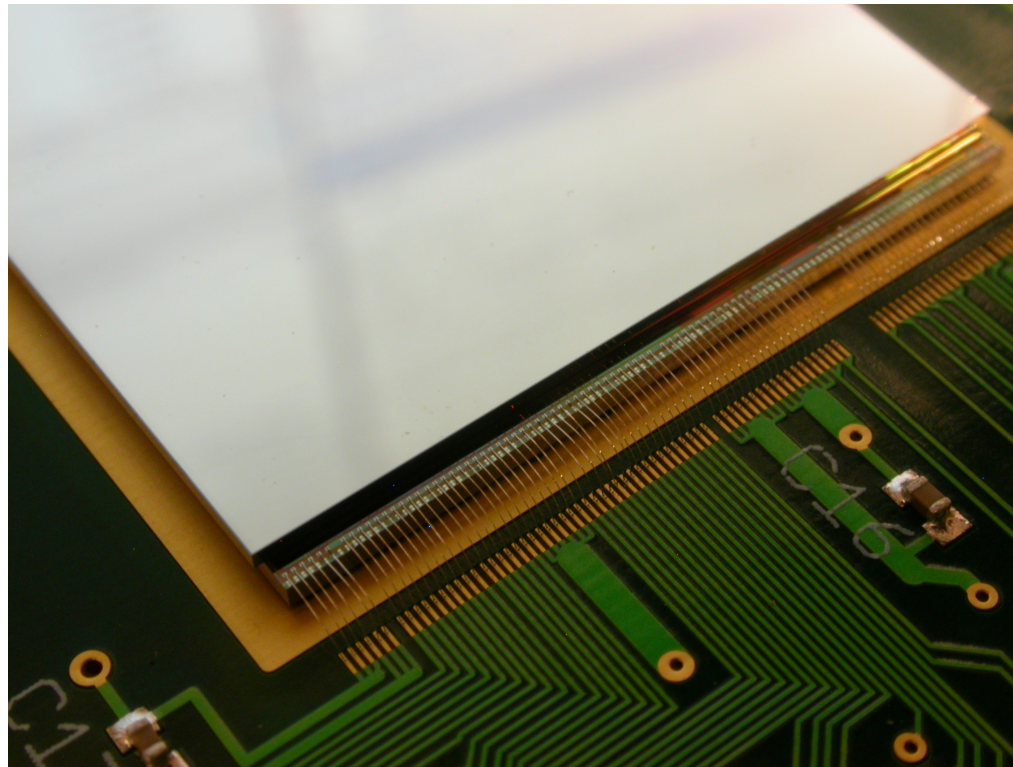


X-Ray Tests of a Pixel Array Detector for Coherent X-Ray Imaging at the Linac Coherent Light Source (LCLS)



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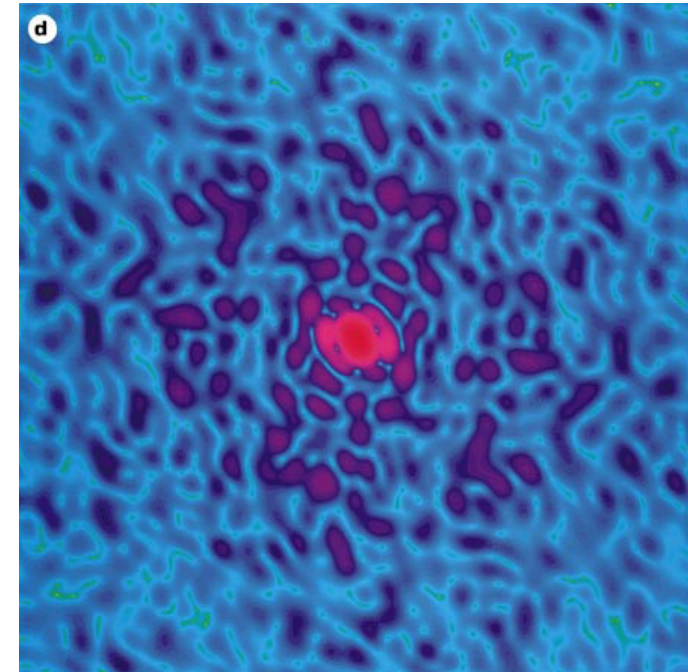
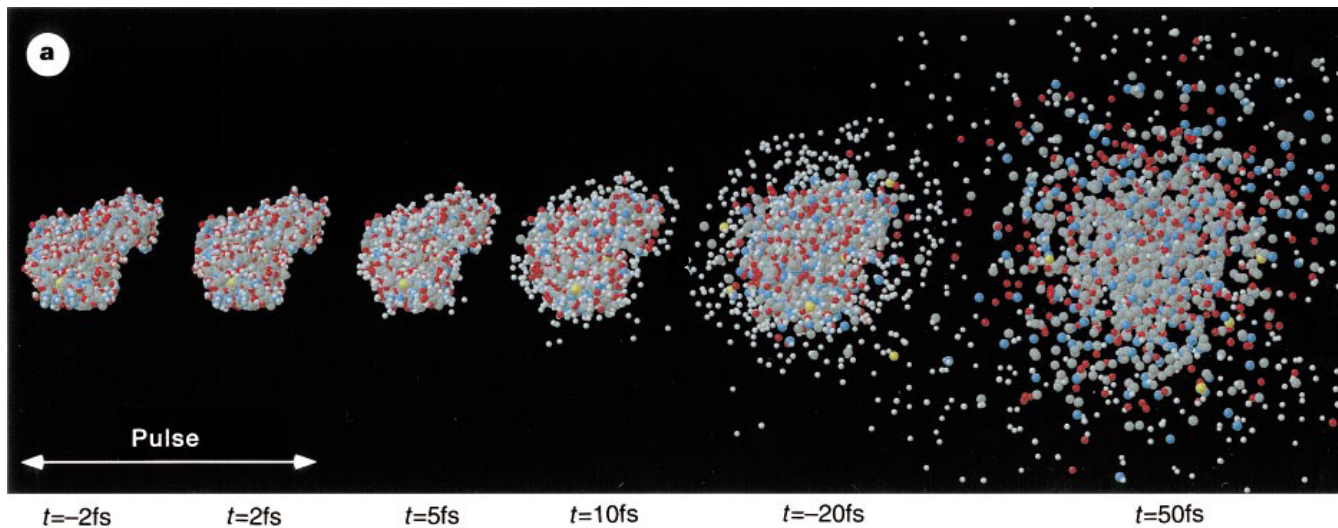
Gruner Biophysics Group – Cornell University
Pixel Conf. 2008 – Sept 24, 2008

Outline

- Coherent imaging experiment at LCLS
- Desired detector characteristics
- Detector approach
- X-ray tests of single ASIC detectors
 - Noise
 - Linearity
 - Spatial response
 - Radiation robustness

Coherent Imaging Experiment

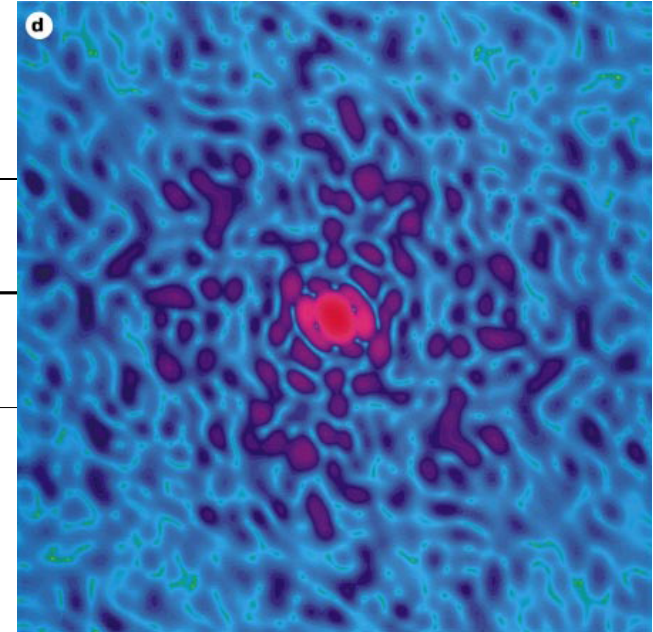
- X-ray Free-Electron Laser (XFEL) at LCLS:
 - Short pulses (femtoseconds)
 - Bright (10^{12} photons/pulse)



R. Neutze, et al. Nature vol 406, pp 752-757 (2000).

Detector Requirements

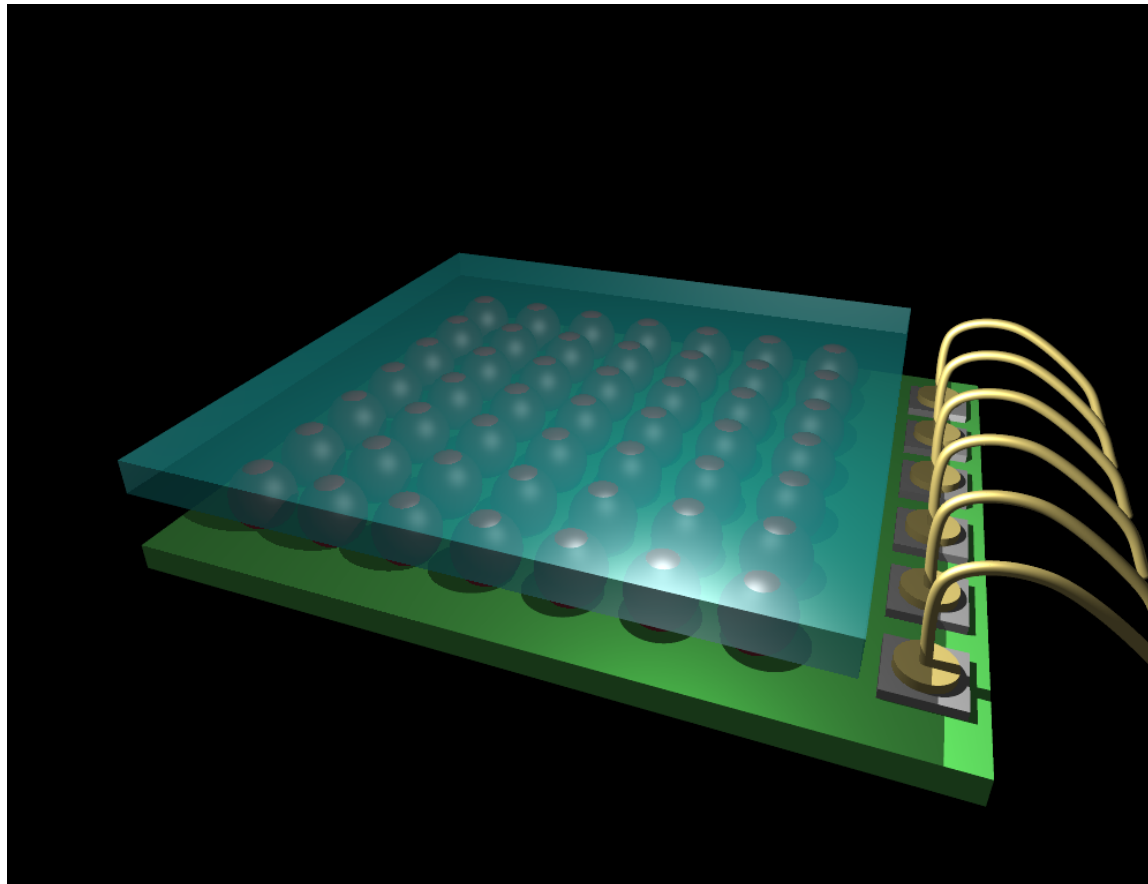
Framing Rate	120 Hz
Pixel Saturation Value	$\approx 1,000$ (8 keV)
Read Noise (RMS)	< 0.33 (8 keV); < 730 e- ENC
Instantaneous Hit Rate	$1e17$ photons/sec/pix
Detector Format	$> 500 \times 500$ pixels
Pixel Size	~ 100 microns
Detector Area	> 50 mm x 50 mm
Quantum Efficiency (at 8 keV)	$> 90\%$
Point-Spread Function	$< 1\%$ to neighbor, $< 0.1\%$ to next neighbor
Radiation Tolerance	65 Mrad (Si) at Detector Face



Hybrid pixel detector (pixel array detector):

Two layers:

- * Fully depleted Si detector (500 μm) thick n-substrate, 5-10 k Ωcm (*SINTEF*)
- * Connecting bump-bonds (*RTI*)
- * ASIC readout (0.25 micron CMOS - *TSMC*)



Framing Rate	120 Hz
Pixel Saturation Value	$\approx 1,000$ (8 keV)
Read Noise (RMS)	< 0.33 (8 keV); < 730 e- ENC

Flexibility of Mixed-Mode CMOS:

- * Per pixel programmable gain
- * A-to-D in each pixel
- * FPGA readout & control

Instantaneous Hit Rate	1e17 photons/sec/pix
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Charge Integrating not Photon Counting

- * 500 microns Si stops 99.9%
- * Spread in over-depleted sensor set by diffusion during drift (RMS 8.1 microns)

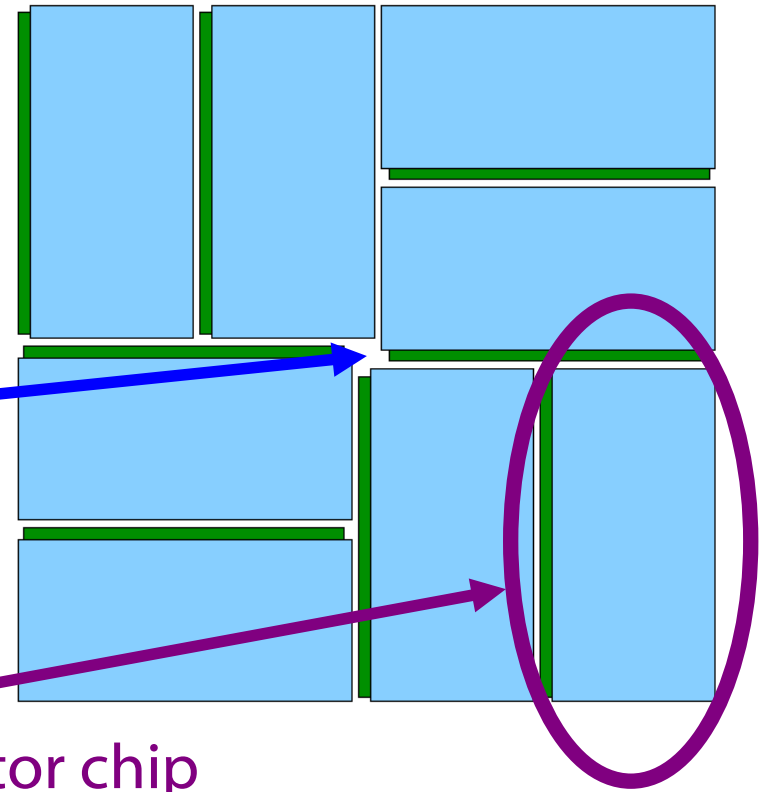
Quantum Efficiency (at 8 keV)	>90% desired. >99% expected
Point-Spread Function	< 1% to neighbor, < 0.1 % to next neighbor
Radiation Tolerance	65 Mrad (Si) at Detector Face

* 16 ASICs, 8 detector chips
185x194 pixels per ASIC
total of 758x758 pixels

* Central Hole
for direct beam

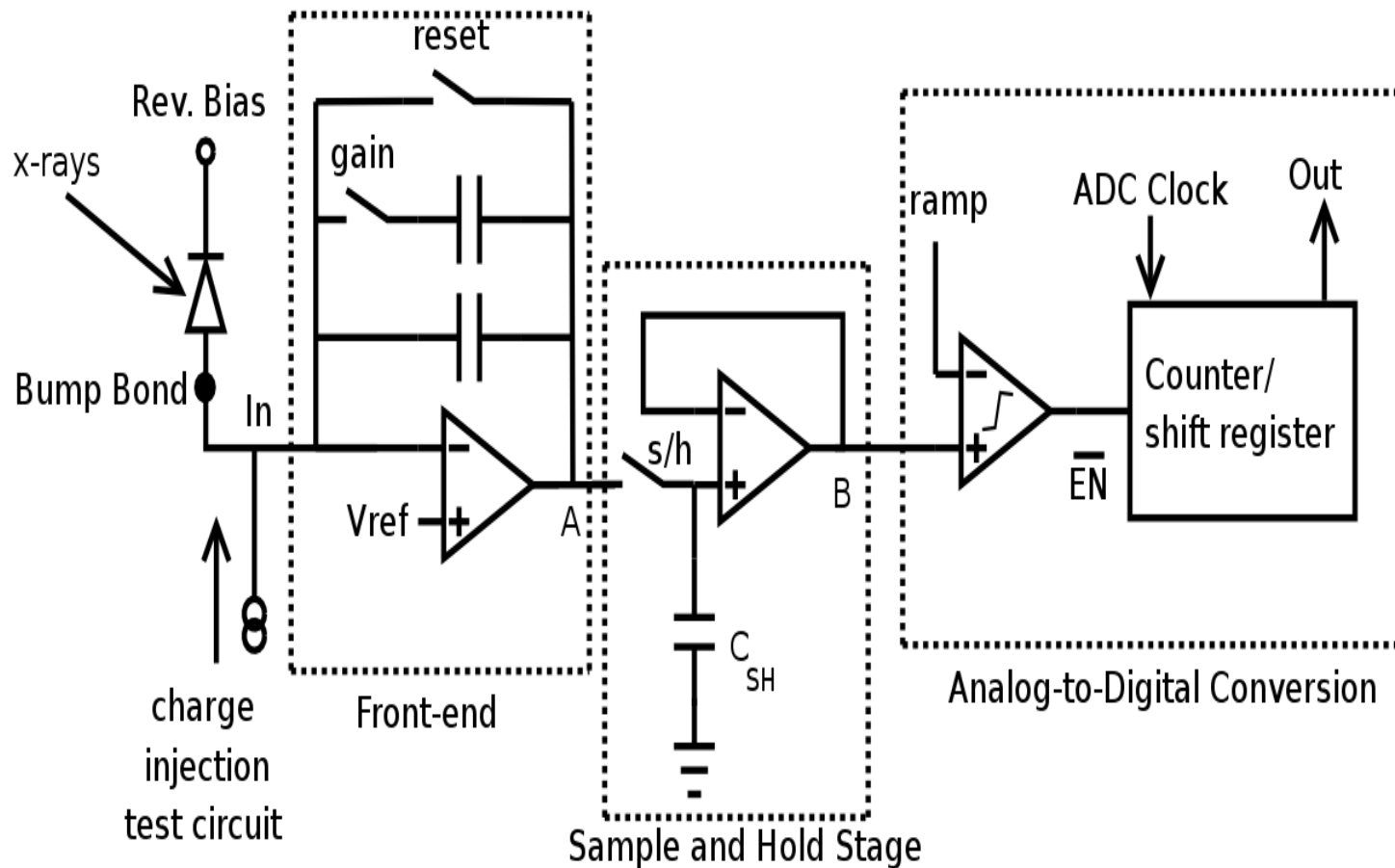
38 nm virus to resolution of 0.3 nm
(oversample by x2)
=> 500 pixels

2 ASICs
1 detector chip



Detector Format	758x758 pixels
Pixel Size	110 microns x 110 microns
Detector Area	83 mm x 83 mm

Pixel Schematic



0.25 μm CMOS

110 x 110 μm
pixel

75 fF: High-gain
565 fF: Low-gain

5 μs integration
window

14-bit conversion

FPGA Control and Acquisition

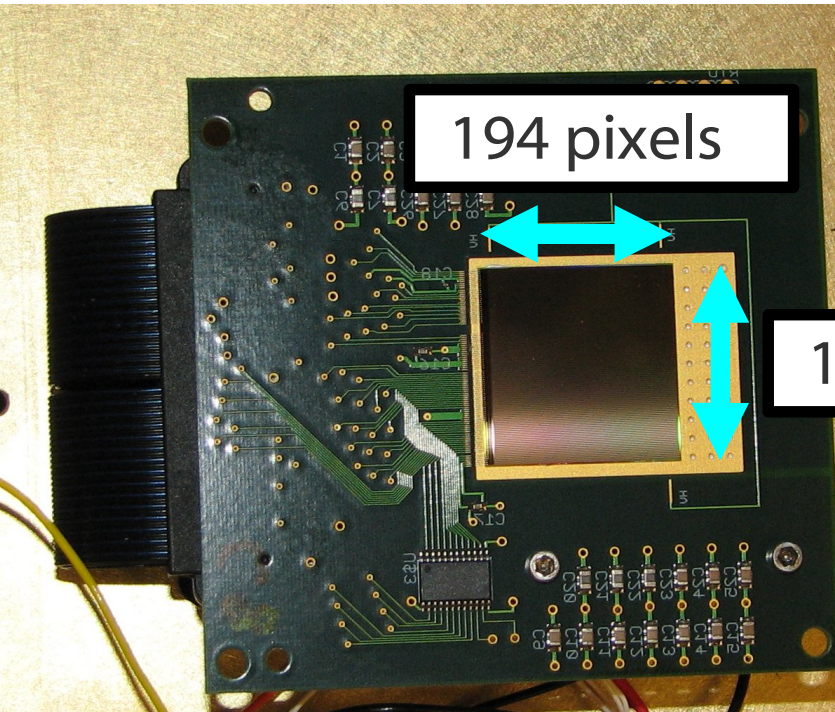
For single ASIC testing:

- * Xilinx Virtex 4 – XCV100FX.
- * Communicates across PCIe bus.
- * Handles configuration
- * Sends control signals during integration and readout
- * Control and Acquisition work separately and in parallel
- * Data from the detector buffered into FPGA block RAM and sent across PCIe bus (DMA)

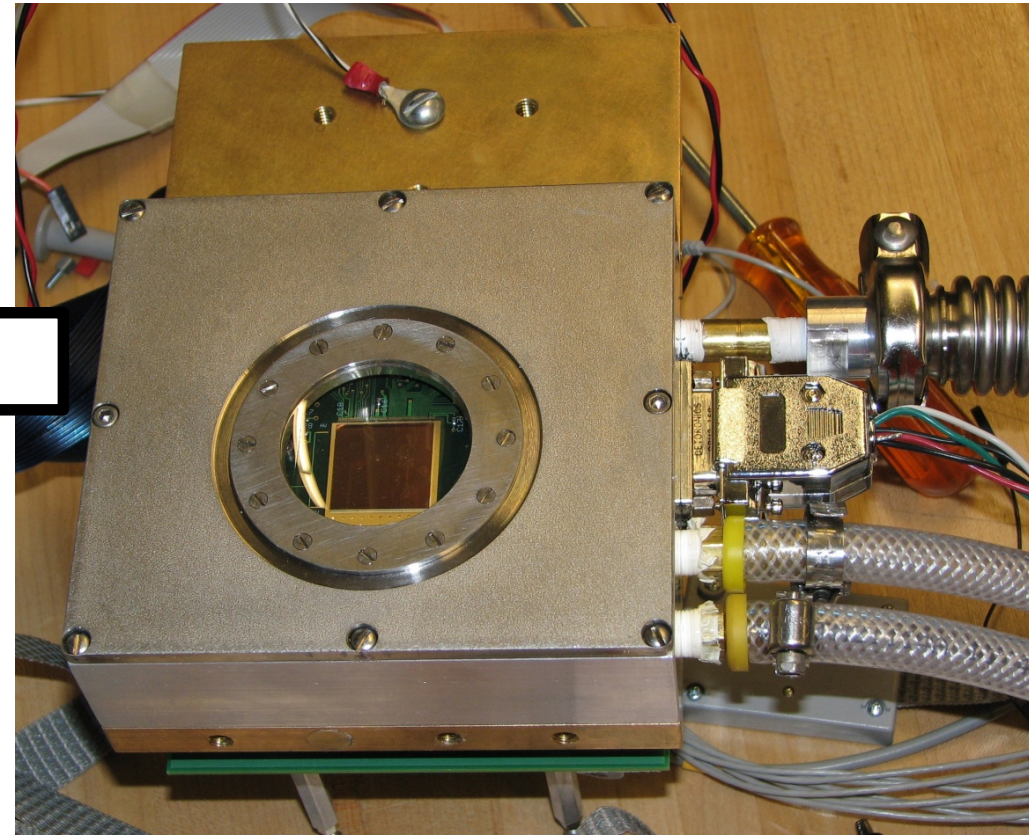
16 ASIC detector:

- * (1 Gb/s) – FPGA uses Scatter/Gather DMA to PC RAM
- * Requires custom disk-controller with continuous rates of 150 MB/s

Single-Chip Testing

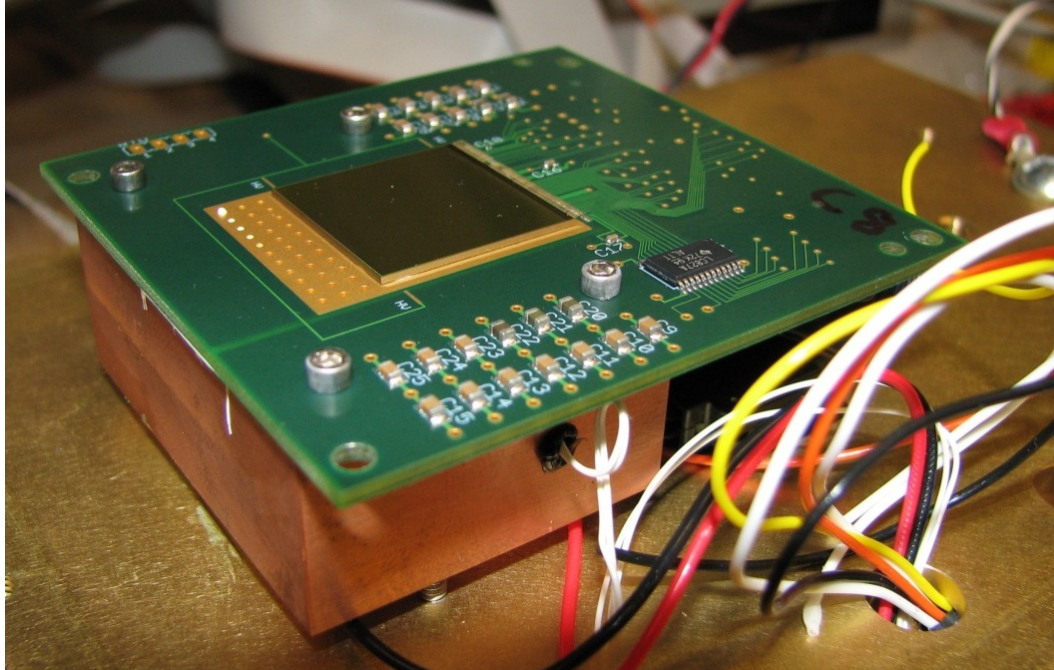


*21 mm x 21 mm chip ASIC
mounted on a daughter-card*



*Detector vacuum cryostat:
Thermoelectric cooling to -30 °C*

Single-Chip Hybrids



Bump-Bonding (RTI):

18 hybrids tested

Median-connectivity:

0.99987 (5 unconnected)

Mean-connectivity:

0.99891

(one hybrid 0.987)

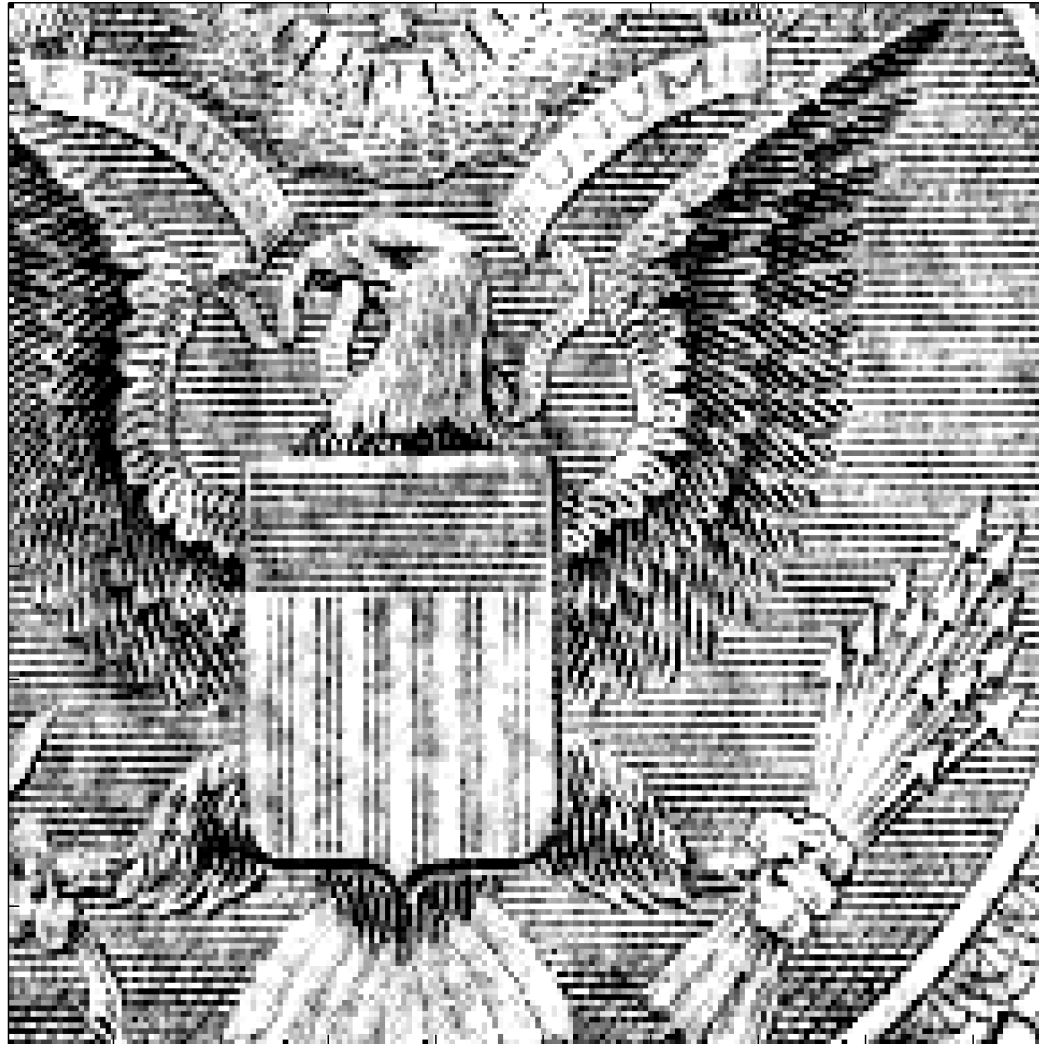
Dark Current:

40 fA/pix (-14 °C)

0.33 nA/cm²

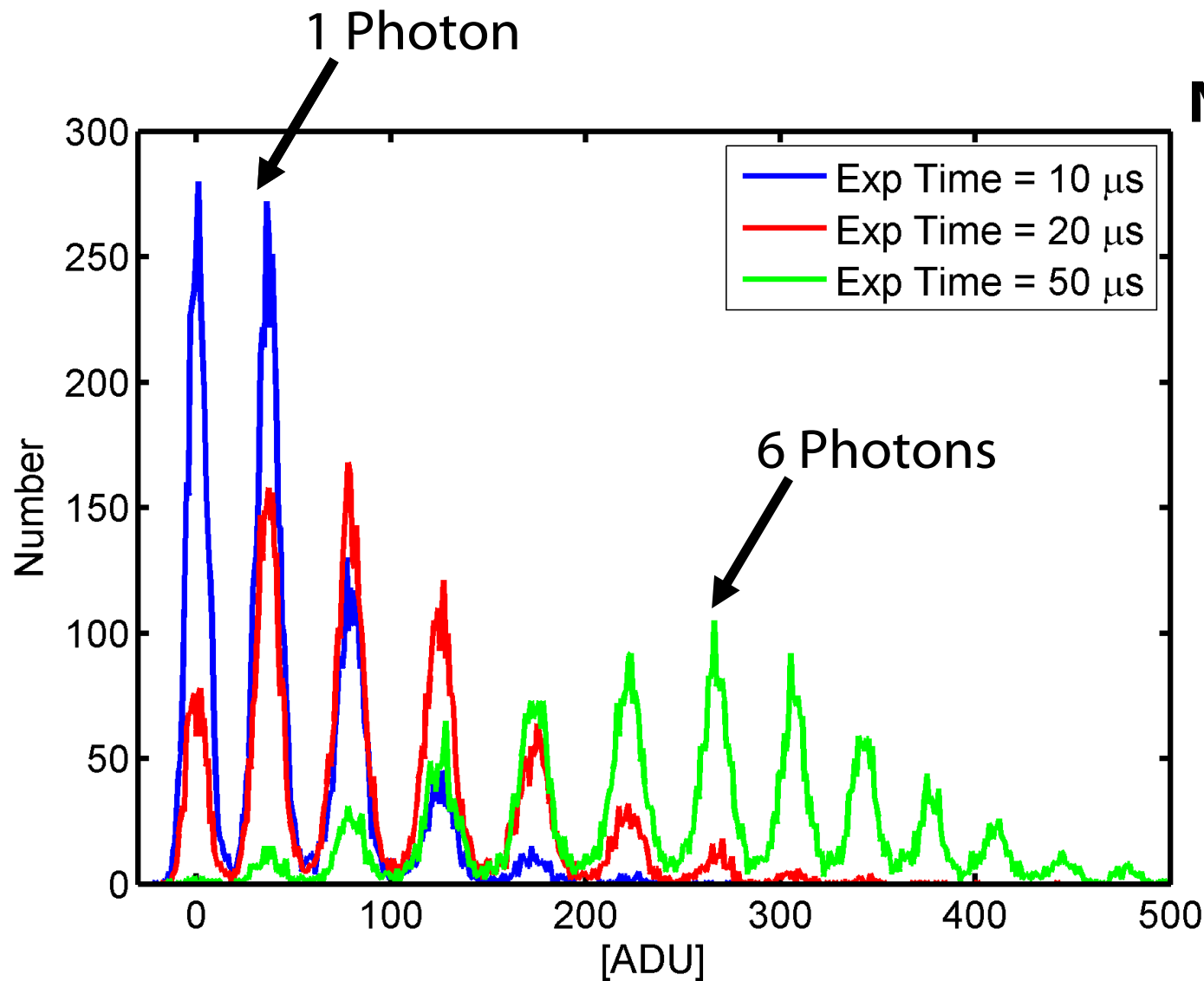
700 fA/pix (18 °C) → 5 μs integration window: 21 e-
6.4 nA/cm²

X-Radiograph of \$1 Bill



- * Taken using Cu K radiation (8 keV)
- * Average of eighty 1.4 second exposures
- * 10% contrast from dark to light

Single Pixel Response Histogram



Noise Characteristics:

High-Gain:

0.15 x-rays RMS
350 e- RMS
2.8 keV FWHM

Low-Gain:

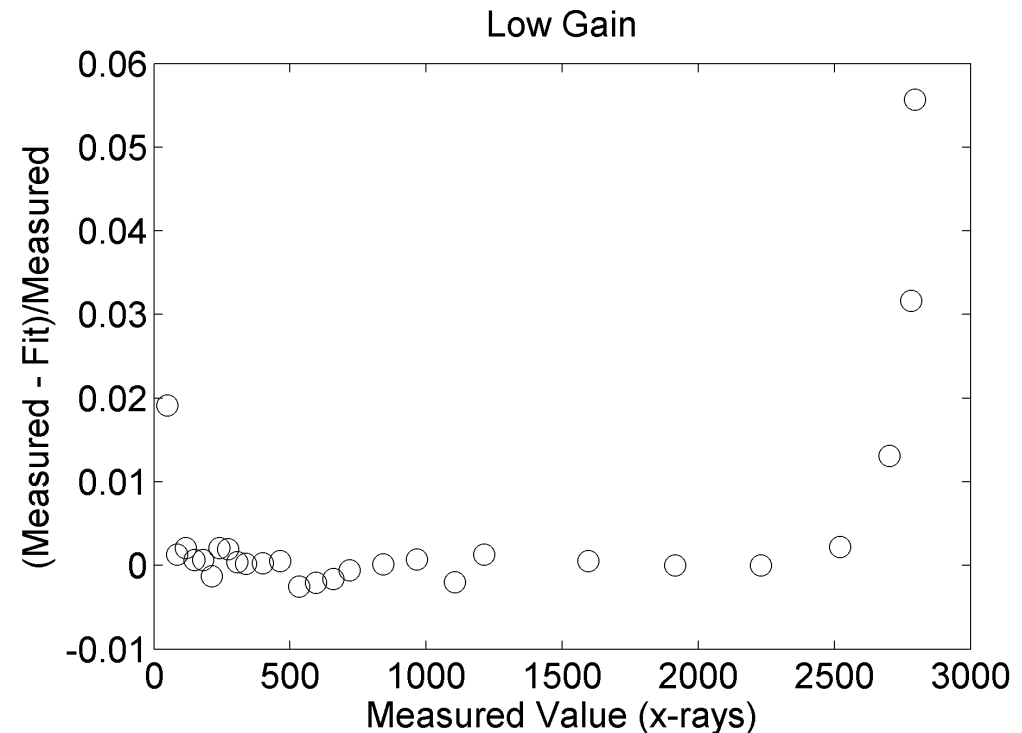
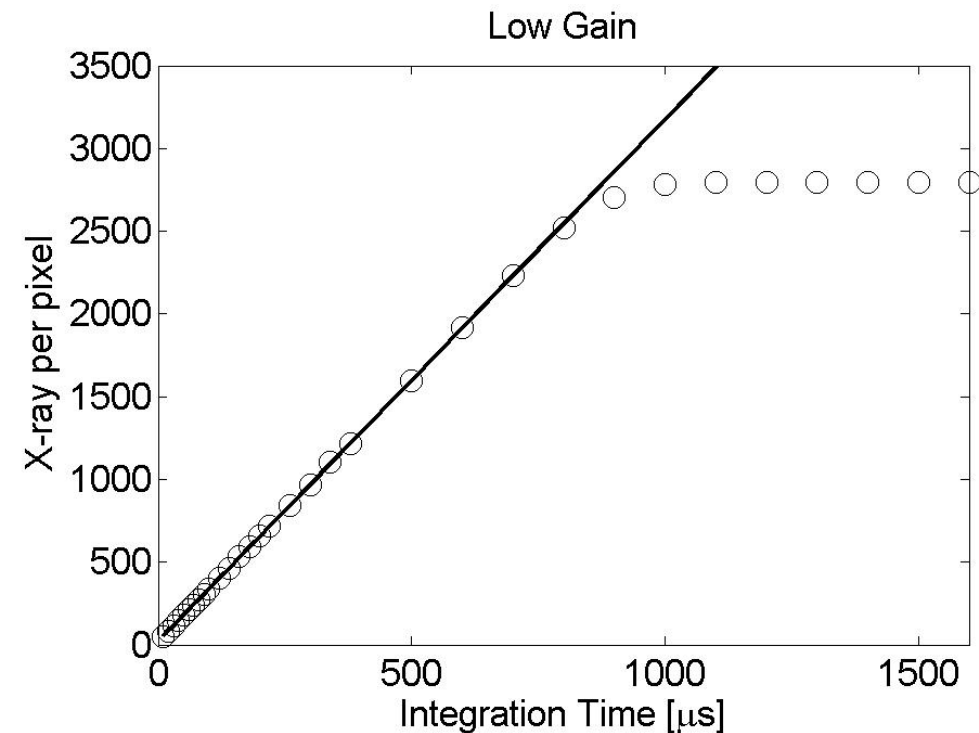
0.46 x-rays RMS
1000 e- RMS

High-Gain mode

8 keV radiation

Single pixel exposed through 25 μ m diameter pinhole

Well-Depth and Linearity

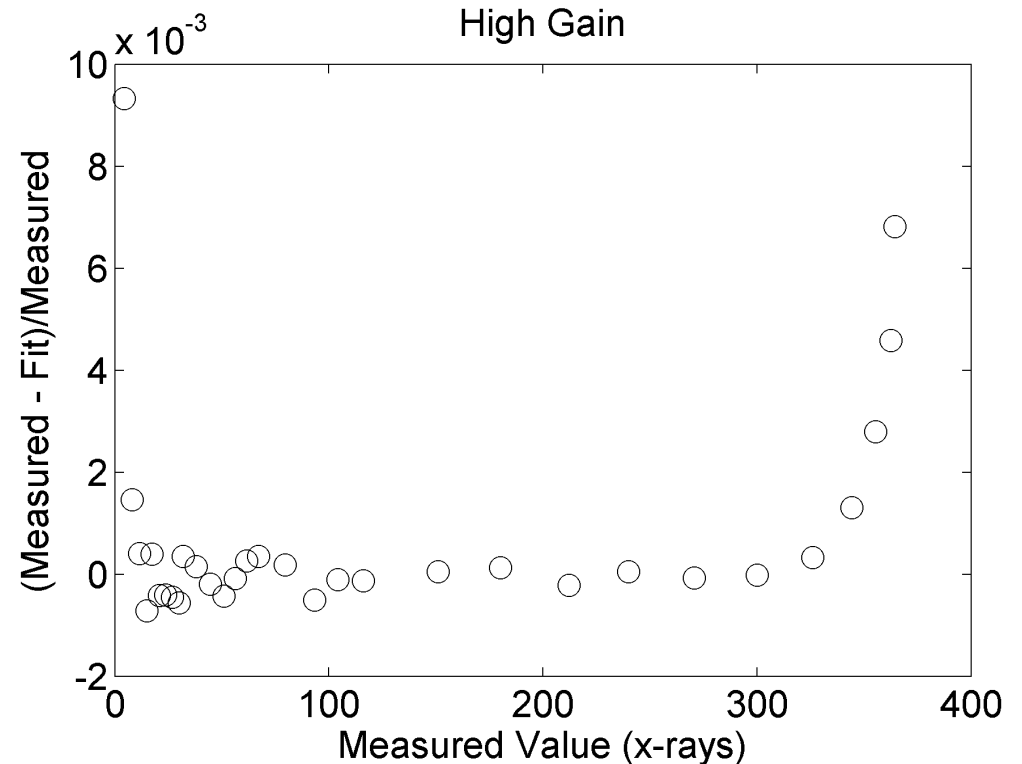
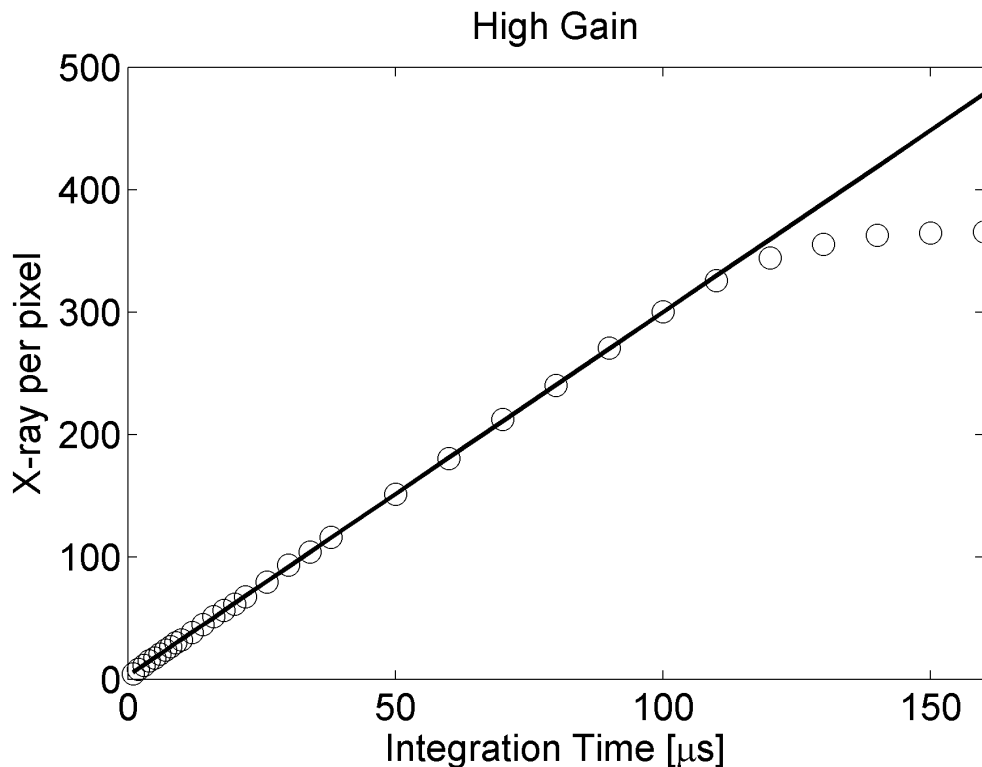


0.35 fC/x-ray and 556 fF \Rightarrow 630 μ V/x-ray gain.

3.3 V supply, 2 V front-end swing \Rightarrow ~3000 x-ray full-well
6.6 M electrons

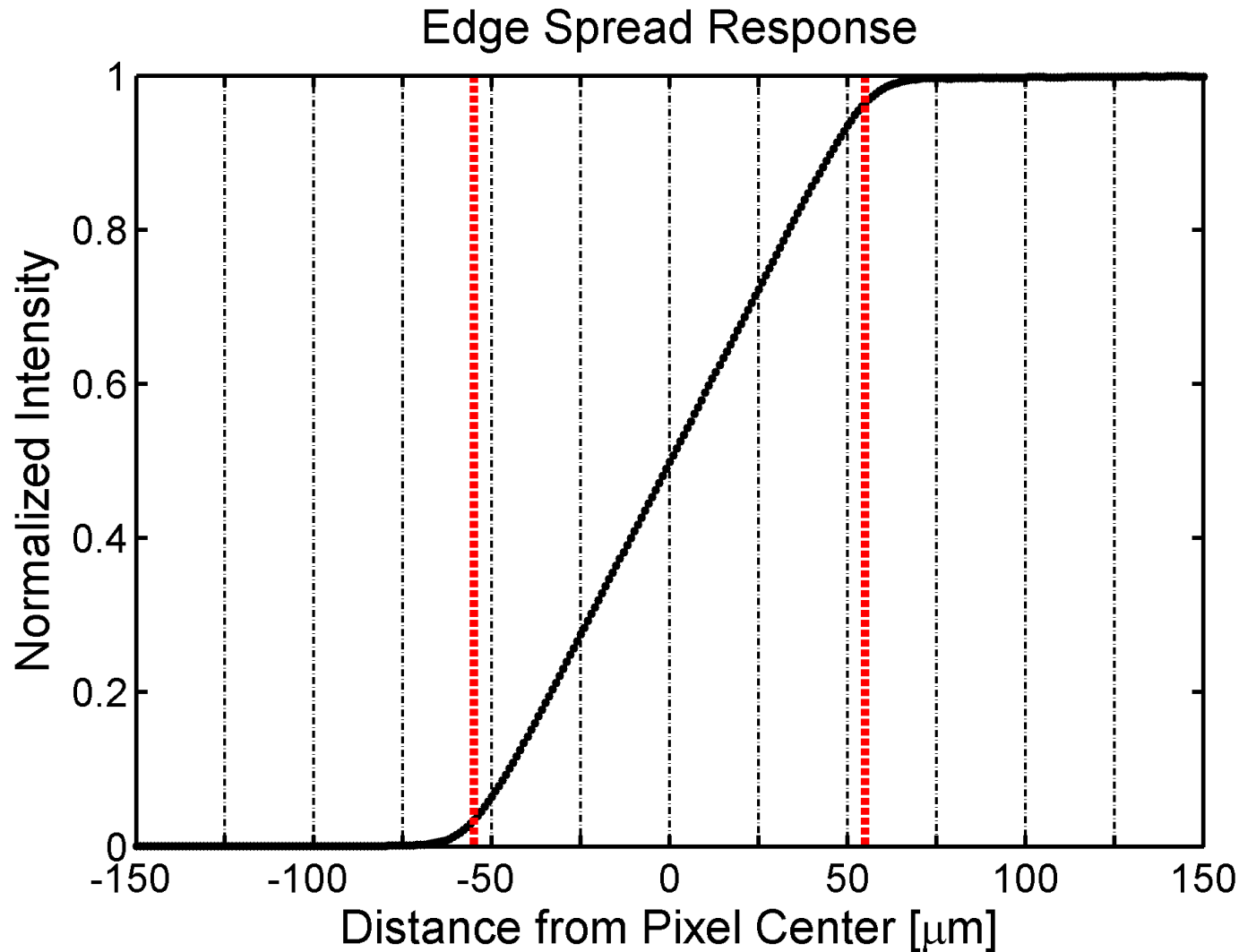
0.15 X-ray read-noise \Rightarrow DR = 20,000 or 86 dB

Well-Depth and Linearity



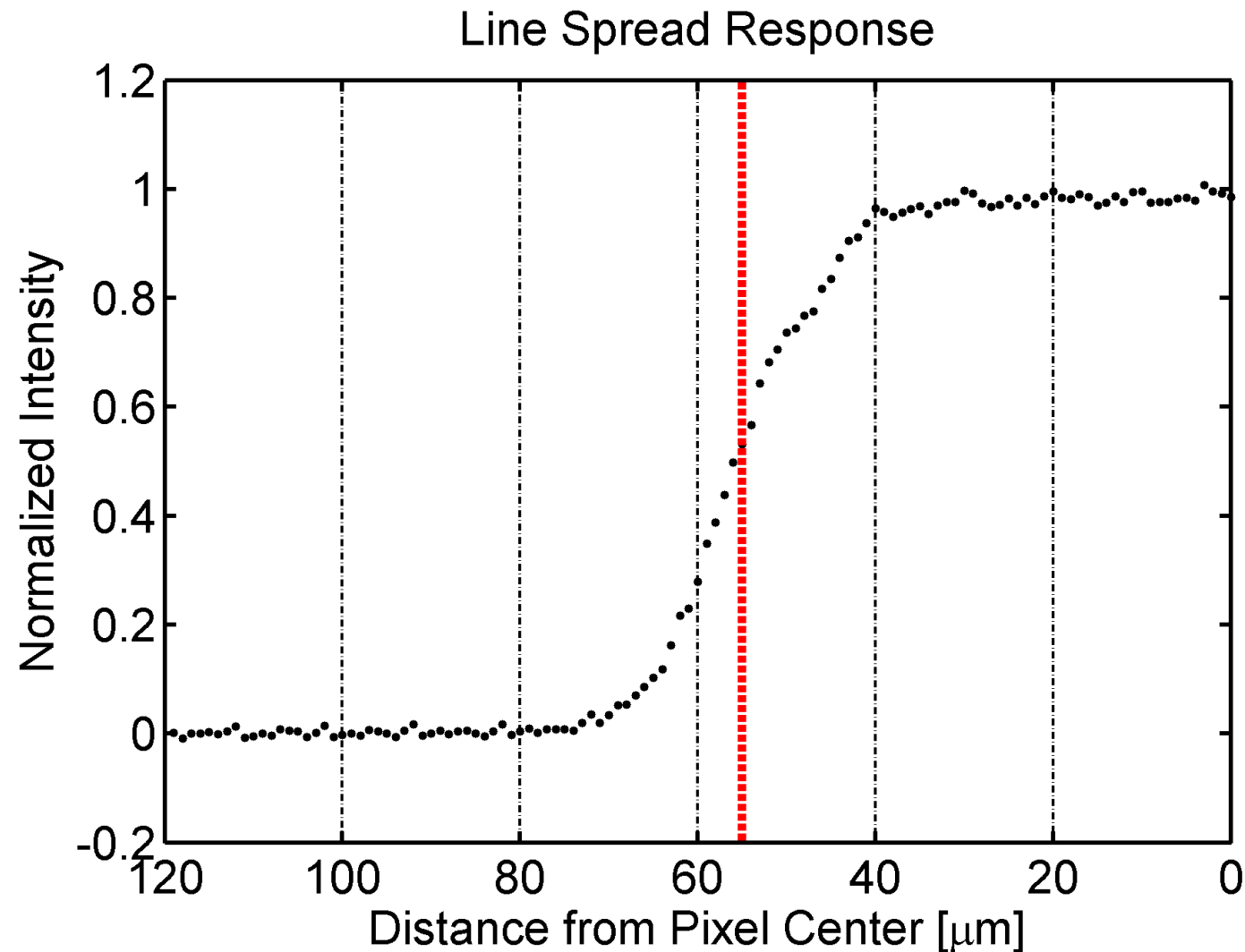
0.35 fC/x-ray and 75 fF \Rightarrow 4.7 mV/x-ray gain.
3.3 V supply, 2 V front-end swing \Rightarrow ~400 x-ray full-well
0.9 M electrons

Spatial Response



- * Measured using knife-edge (inclined slightly from detector axis)
- * Combined with translation in few micron steps
- * Red-lines denote pixel boundary

Spatial Response



- * Gradient of edge-spread gives line-spread
- * Spreading to 5% level extends to 15 μm past pixel border

Radiation Robustness

Bare ASICs dosed to 400 kRad (Si) [electrically biased at 12 °C]:

- * CMOS readout showed problems at levels of 140 kRad (Si)

Annealing:

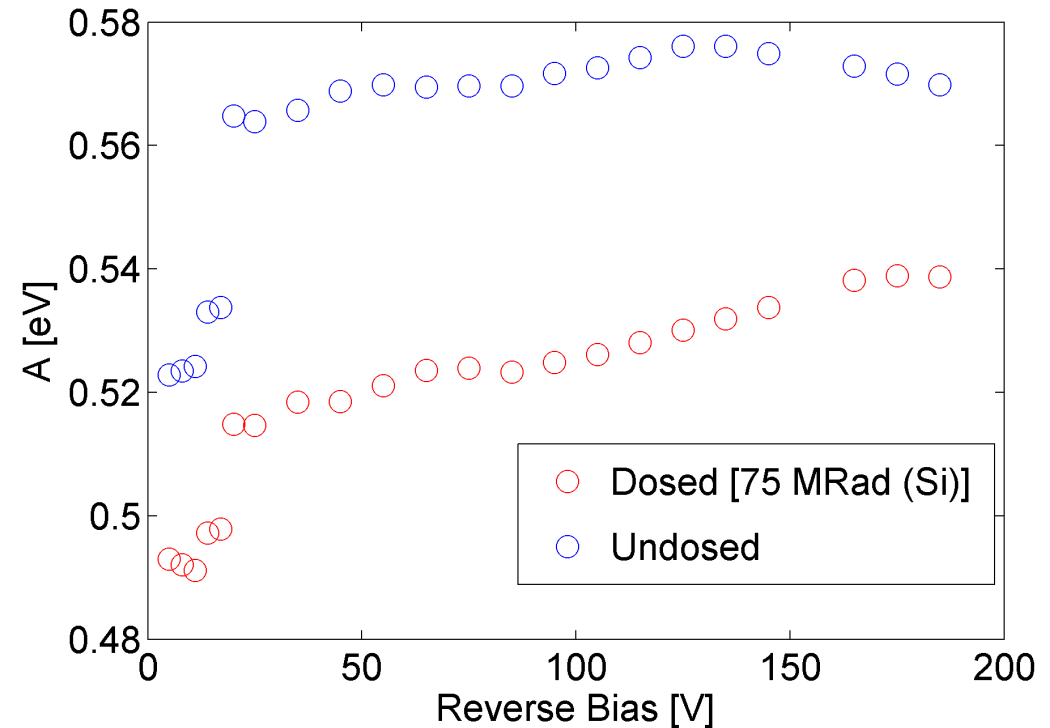
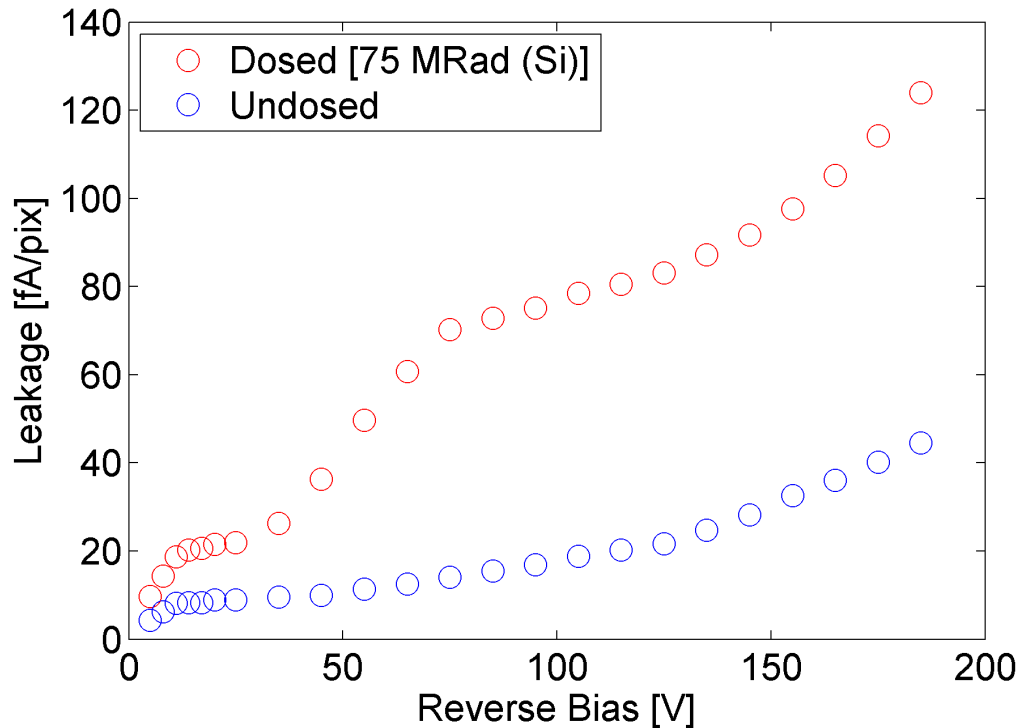
- * room temperature anneals (40 days unbiased)
 - almost all effects vanish
- * 56 °C one-day anneal removed all residual signs of damage

Damage and annealing suggest hole-trapping, possibly activating parasitic transistors through the field-oxide

Hybrids dosed to 75 Mrad (Si):

leakage currents increased, CMOS readout showed few signs of damage

Detector Leakage



* $T = -14\text{ }^{\circ}\text{C}$

(same I-V scan at nine temperatures)

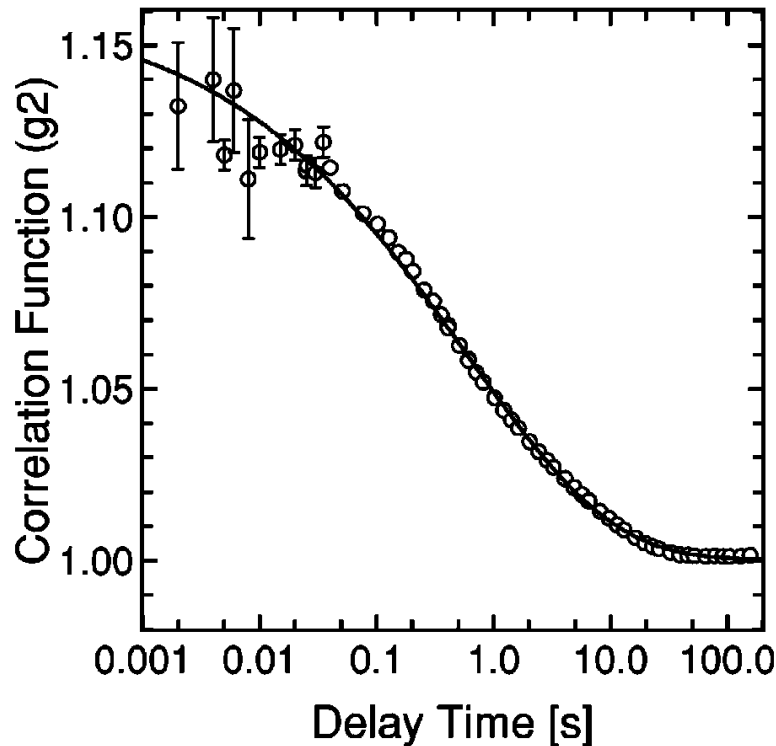
* 65 kRad (Si) at pixel electrodes

$$I \propto e^{(-A/kT)}$$

slope: $\log(I)$ vs. $1/kT$

$$E_g(\text{Si}) = 1.12\text{ eV}$$

X-ray Photon Correlation Spectroscopy



Falus, Borthwick, Mochrie, RSI (2004) **75**, 4383-4400.

Minimum correlation time: 2 ms
Limited by detector read-out time.

- X-Ray photon correlation spectroscopy is used to study complex dynamics at the nanometer scale.
- How do the nanoscale interactions produce the macroscopic properties we observe?
- Systems of interest include:
 - polymer creeping
 - protein folding
- Nanoscale systems move **faster** than millisecond time scales!

Summary

- Integrating pixel-array detector being developed for LCLS
- 2 cm x 2 cm (194x185 pixels) detectors tested:
 - ENC of 350 e⁻
 - Full-well up to 6.6 M e⁻
 - Charge sharing region of 15 microns
 - Frame-rates of 8 ms
 - Excellent bump-bonding results

Acknowledgements

- Cornell LCLS team:
Hugh Philipp, Marianne Hromalik, Mark Tate, Sol Gruner
- Other Cornell Detector members:
Current: Darol Chamberlain, Kate Green,
Former: Daniel Schuette, Alper Ercan
- Stanford/SLAC/LCLS
- Funding: DOE-BES, DOE-BER
- RTI
- SINTEF
- MOSIS

END